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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/660,565	09/12/2003	Howard Rhodes	M4065.0570/P570-A	5308	
24998	7590 04/22/2005		EXAMINER		
	N SHAPIRO MORIN &	VU, QUANG D			
2101 L Stree Washington,	DC 20037		ART UNIT	PAPER NUMBER	
-		•	2811		
			DATE MAILED: 04/22/2005		

Please find below and/or attached an Office communication concerning this application or proceeding.

Advisory Action Before the Filing of an Appeal Brief

Application No.	Applicant(s)
10/660,565	RHODES ET AL.
Examiner	Art Unit
Quang D. Vu	2811

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	Quang D. Vu	2811	
The MAILING DATE of this communication appe	ears on the cover sheet with the o	correspondence add	ress
THE REPLY FILED <u>29 March 2005</u> FAILS TO PLACE THIS AF	PPLICATION IN CONDITION FOR	ALLOWANCE.	
1. The reply was filed after a final rejection, but prior to or or this application, applicant must timely file one of the follow places the application in condition for allowance; (2) a Not a Request for Continued Examination (RCE) in compliant time periods:	wing replies: (1) an amendment, aft otice of Appeal (with appeal fee) in a	fidavit, or other evider compliance with 37 C	nce, which FR 41.31; or (3)
 a) The period for reply expires 3 months from the mailing date b) The period for reply expires on: (1) the mailing date of this A 		in the final rejection, wh	ichever is later. In
no event, however, will the statutory period for reply expire I Examiner Note: If box 1 is checked, check either box (a) or		•	
TWO MONTHS OF THE FINAL REJECTION. See MPEP 7		100(-) 4 45	de endemaion for
Extensions of time may be obtained under 37 CFR 1.136(a). The date have been filed is the date for purposes of determining the period of exunder 37 CFR 1.17(a) is calculated from: (1) the expiration date of the set forth in (b) above, if checked. Any reply received by the Office late may reduce any earned patent term adjustment. See 37 CFR 1.704(b) NOTICE OF APPEAL	tension and the corresponding amount shortened statutory period for reply orig r than three months after the mailing da	of the fee. The appropr inally set in the final Offi	iate extension fee ice action; or (2) as
 The Notice of Appeal was filed on A brief in complifing the Notice of Appeal (37 CFR 41.37(a)), or any external a Notice of Appeal has been filed, any reply must be filed. 	ension thereof (37 CFR 41.37(e)), to	avoid dismissal of th	
AMENDMENTS			
 The proposed amendment(s) filed after a final rejection, (a) They raise new issues that would require further contains 			ecause
(b) They raise the issue of new matter (see NOTE below		TE Delow),	
(c) They are not deemed to place the application in be appeal; and/or	•	educing or simplifying	the issues for
(d) They present additional claims without canceling a NOTE: (See 37 CFR 1.116 and 41.33(a)).		jected claims.	
4. The amendments are not in compliance with 37 CFR 1.1		ompliant Amendment	(PTOL-324)
5. Applicant's reply has overcome the following rejection(s		mphant / monamont	(1.102.02.1).
 Newly proposed or amended claim(s) would be a non-allowable claim(s). 		timely filed amendme	ent canceling the
7. For purposes of appeal, the proposed amendment(s): a) how the new or amended claims would be rejected is pro The status of the claim(s) is (or will be) as follows: Claim(s) allowed: Claim(s) objected to: Claim(s) rejected: 90 and 93-141. Claim(s) withdrawn from consideration:		ill be entered and an o	explanation of
AFFIDAVIT OR OTHER EVIDENCE			
 The affidavit or other evidence filed after a final action, by because applicant failed to provide a showing of good an was not earlier presented. See 37 CFR 1.116(e). 			
9. The affidavit or other evidence filed after the date of filing entered because the affidavit or other evidence failed to showing a good and sufficient reasons why it is necessar	overcome <u>all</u> rejections under appery and was not earlier presented. S	al and/or appellant fa See 37 CFR 41.33(d)(ils to provide a 1).
10. ☐ The affidavit or other evidence is entered. An explanation REQUEST FOR RECONSIDERATION/OTHER			
 The request for reconsideration has been considered by <u>See Continuation Sheet.</u> 	ut does NOT place the application i	n condition for allowa	nce because:
12. Note the attached Information Disclosure Statement(s).	(PTO/SB/08 or PTO-1449) Paper I	Vo(s).	
13. Other:		1,4	
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TECHNOLOGY CENTER 2800

Continuation of 11. does NOT place the application in condition for allowance because: It is argued, in page 3 of the remarks, that Rhodes does not teach or suggest forming a floating diffusion region for receiving charge from the charge collection region; and forming a charge storage capacitor over the semiconductor substrate so that one electrode of the storage capacitor is connected to the floating diffusion region by an electrical contact. This argument is not convincing because Rhodes (figures 1-14) teaches forming a floating diffusion region (130) for receiving charge from the charge collection region (155) (Rhodes teaches doped region [126], which is connected photogate transistor [125] to the transfer transistor gate [128]; [155] is a part of the transistor [125] and [130] is a part of the transistor [128]. So, [155] is connected to the [130]. Therefore, a floating diffusion region [130] receives charge from the charge collection region [155]); and forming a charge storage capacitor (162) over the semiconductor substrate (116, 120) so that one electrode (156) of the storage capacitor (162) is connected to the floating diffusion region (130) by an electrical contact (150).

It is argued, in page 3 of the remarks, that Rhodes and Doyle et al. do not teach or suggest the trench and planar capacitor structures that are all formed overlying the active area of the pixel sensor cell, and not such that the entire extent of the charge storage capacitor overlies the field oxide region. This argument is not convincing because the applicant fails to define the trench and planar capacitor structures that are all formed overlying the active area of the pixel sensor cell in the claimed limitations of claim 130. However, the combined device (Rhodes and Doyle et al.) includes forming a charge storage capacitor (Doyle et al.; C2) such that the entire extent of the charge storage capacitor (Doyle et al.; C2) overlies the field oxide region (Doyle et al.; 40) for the reason that is discussed in the final office.

It is argued, in page 4 of the remarks, that Rhodes does not teach or suggest connecting an electrode of a storage capacitor to a floating diffusion region by a first electrical contact. This argument is not convincing because the applicant fails to define connecting an electrode of a storage capacitor to a floating diffusion region by a first electrical contact in the claimed limitations of claim 137. However, Rhodes (figures 1-14) includes connecting an electrode of a first charge storage capacitor (capacitors [64, 74]; figure 1) to the floating diffusion region (130) by a first electrical contact (42) (floating diffusion region [130] connects to a readout circuit [60]; column 7, lines 42-54).

It is argued, in page 6 of the remarks, that Rhodes and Doyle et al. do not teach or suggest forming a charge storage capacitor such that the entire extent of the charge storage capacitor overlies the field oxide region and forming a contact between the first doped region and the charge storage capacitor. This argument is not convincing because the combined device (Rhodes and Doyle et al.) includes forming a contact (Rhodes; 150) between the first doped region (Rhodes; 155) and the charge storage capacitor (Rhodes; 162) and forming a charge storage capacitor (Doyle et al.; C2) such that the entire extent of the charge storage capacitor (Doyle et al.; C2) overlies the field oxide region (Doyle et al.; 40) for the reason that is discussed in the final office.